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NSN 5961-00-391-1054 Thyristor Semiconductor Device - Page 1 of 1



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View Online at https://aerobasegroup.com/nsn/5961-00-391-1054
Inclosure Material:
Metal
Overall Length:
Between 0.874 inches and 1.030 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 1.049 inches and 1.062 inches
Thread Size:
0.500 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
800.0 repetitive peak reverse voltage and 960.0 nonrepetitive peak reverse voltage and 800.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
10.00 milliamperes forward current, average nanoamperes and 10.00 milliamperes forward current, total rms and 110.00 amperes forward
current, total rms horsepower metric and 1600.00 amperes forward current, total rms watts
Power Rating Per Characteristic:
400.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius case
Special Features:
Junction pattern arrangement: pnpn
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig: